#### TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TD62476P,TD62477P,TD62478P,TD62479P

#### 2CH PERIPHERAL AND / NAND / OR / NOR DRIVERS

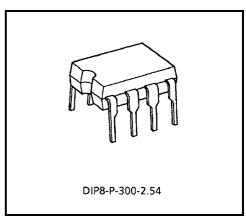
The TD62476P, TD62477P, TD62478P, TD62479P are comprised of two NPN single output stages and control inputs which can gate the outputs.

All units feature integral clamp diodes for switching inductive loads

Applications include relay, hammer, lamp and display (LED) drivers.

#### **FEATURES**

- Output current (single output) 350 mA (Max)
- High sustaining voltage output 35 V (Min)
- Output clamp diodes
- Inputs compatible with TTL and 5 V CMOS
- Standard supply voltage
- Package type-P: DIP-8 pin

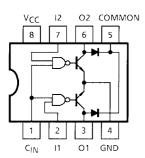


Weight: 0.45 g (Typ.)

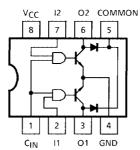
	TD6247	6P	TD62477P			TD62478P			TD62479P			
INPUT		OUTPUT	INPUT		OUTPUT	INPUT		OUTPUT	INPUT		OUTPUT	
$C_IN$	ı	0011 01	C <sub>IN</sub>		0011 01	C <sub>IN</sub>		0011 01	C <sub>IN</sub>		0011 01	
0	0	ON	0	0	OFF	0	0	ON	0	0	OFF	
0	1	OFF	0	1	OFF	0	1	OFF	0	1	ON	
1	0	OFF	1	0	OFF	1	0	OFF	1	0	ON	
1	1	OFF	1	1	ON	1	1	OFF	1	1	ON	

# **PIN CONNECTION (TOP VIEW)**

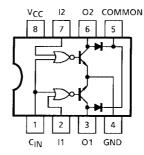




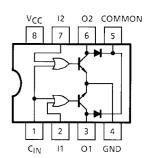
TD62477P



TD62478P

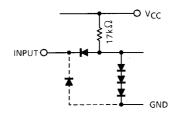


TD62479P

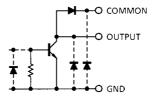


# **EQUIVALENT OF INPUTS AND OUTPUTS**

#### Equivalent of inputs



#### Equivalent of outputs



Note: The input and output parasitic diodes cannot be used as clamp diodes.

# **MAXIMUM RATINGS (Ta = 25°C)**

CHARACTERISTICS	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	-0.5~7.0	V
Input Voltage	V <sub>IN</sub>	-0.5~5.5	V
Output Sustaining Voltage	V <sub>CE</sub> (SUS)	-0.5~35	٧
Output Current	lout	350	mA / ch
Clamp Diode Reverse Voltage	V <sub>R</sub>	35	V
Clamp Diode Forward Current	l <sub>F</sub>	300	mA
Power Dissipation	P <sub>D</sub> (Note)	0.9	W
Operating Temperature	T <sub>opr</sub>	-30~75	°C
Storage Temperature	T <sub>stg</sub>	-55~150	°C

Note: Delated above 25°C in the proportion of 7.2 mW / °C.

# RECOMMENDED OPERATING CONDITIONS (Ta = -30~75°C)

CHARACTERISTIC	SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT
Supply Voltage	V <sub>CC</sub>	_	4.5	5.0	5.5	V
Output Sustaining Voltage	V <sub>CE</sub> (SUS)	_	0	_	35	V
Output Current	lour	DC 1 Circuit	0	_	300	mA /
Output Current	Гоит	DC 2 Circuits	0	_	200	ch
Input Voltage	V <sub>IN</sub>	_	4.5	_	V <sub>CC</sub>	V
Clamp Diode Reverse Voltage	V <sub>R</sub>	_	_	_	35	V
Clamp Diode Forward Current	I <sub>F</sub>	_	_	_	300	mA
Power Dissipation	PD	_	_	_	0.4	W

2

# **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

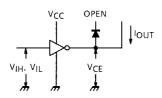
CHARACTERISTIC			SYMBOL	TEST CIR- CUIT	TEST CO	NOITIONC	MIN	TYP.	MAX	UNIT	
Input Voltage		"H" Level		V <sub>IH</sub>	1	_		2.0	_	_	V
iriput voita	ge	"L" Level		V <sub>IL</sub>	1	_		-	_	0.8	·
Output Current		"H" Level		ІОН	2	V <sub>CC</sub> = 4.5V, V <sub>IH</sub> = 2.0 V V <sub>IL</sub> = 0.8V, V <sub>OH</sub> = 35 V		_	_	10	μΑ
						V <sub>CC</sub> = 4.5 V	I <sub>OUT</sub> = 100 mA	_	0.15	0.30	
Output Voltage		"L" Level		V <sub>OL</sub>	3	$V_{IH} = 2.0 \text{ V}$	I <sub>OUT</sub> = 200 mA	_	0.28	0.45	V
						$V_{IL} = 0.8 V$	I <sub>OUT</sub> = 300 mA	-	0.45	0.60	
			/el	I <sub>IH</sub>	4	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 5.5 V		_	_	10	μA
Input Current		"L" I	I	I <sub>IL</sub>	5	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.4 V		_	-0.26	-0.4	- mA
		Level C <sub>IN</sub>						-	-0.52	-0.8	
Clamp Diode Reverse Current			I <sub>R</sub>	6	$V_{CC}$ = 4.5 V, $V_R$ = 35 V		_	_	10	μA	
Clamp Diode Forward Voltage			V <sub>F</sub>	7	V <sub>CC</sub> = 4.5 V, I <sub>F</sub> = 300 mA		_	1.5	1.75	٧	
		TD62476P					V <sub>IN</sub> = 5 V	-	8.4	14	
	Output	TD624	77P		5	– V <sub>CC</sub> = 5.5 V	V <sub>IN</sub> = 0 V	-	0.6	0.85	mA
	Off	TD624	78P	Іссн			V <sub>IN</sub> = 5 V	-	9	14	
Supply		TD624	79P				V <sub>IN</sub> = 0 V	1	1.1	1.8	
Current	Output On	TD624	76P		4		V <sub>IN</sub> = 5 V	_	38	55	
		t TD6247	77P				V <sub>IN</sub> = 0 V	_	36	53	
		TD624	78P	ICCL			V <sub>IN</sub> = 5 V	_	39	56	
		TD624	79P				V <sub>IN</sub> = 0 V	_	36	63	

# **SWITCHING CHARACTERISTICS (Ta = 25°C)**

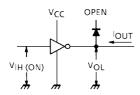
CHARACTERIS	SYMBOL	TEST CIR- CUIT	CONDITION	MIN	TYP.	MAX	UNIT	
Propagation Delay	"H" Level	t <sub>pLH</sub>	_	C. = 15 pE P. = 1200	_	0.7	_	us
Time	"L" Level	t <sub>pHL</sub>	_	$C_L = 15 \text{ pF}, R_L = 120\Omega$	_	0.2	_	μδ

#### **TEST CIRCUIT**

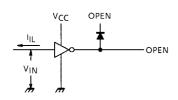
# 1. VIH, VIL



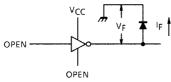
#### 3. VOL



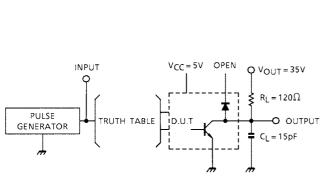
### 5. I<sub>IL</sub>, I<sub>CCH</sub>



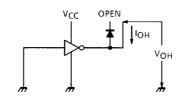
### 7. V<sub>F</sub>



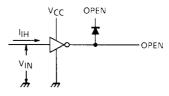
### **TEST CIRCUIT OF SWITCHING CHARACTERISTIC**



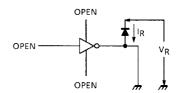
# 2. I<sub>OH</sub>



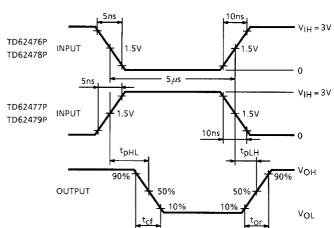
#### 4. I<sub>IH</sub>, I<sub>CCL</sub>



#### 6. I<sub>R</sub>



#### **TEST WAVEFORM**



#### PRECAUTIONS for USING

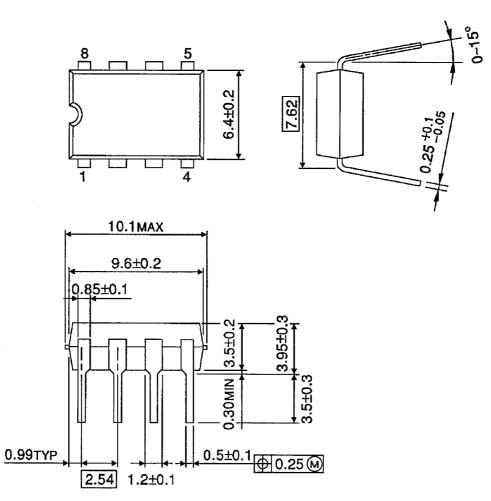
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

Utmost care is necessary in the design of the output line, VCC, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding

# **PACKAGE DIMENSIONS**

DIP8-P-300-2.54 Unit: mm



5

Weight: 0.45 g (Typ.)

2001-07-04

#### **RESTRICTIONS ON PRODUCT USE**

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
  rights of the third parties which may result from its use. No license is granted by implication or otherwise under
  any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.